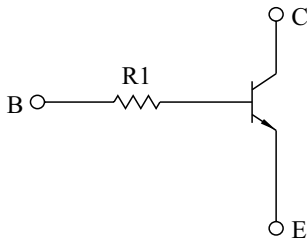


SWITCHING APPLICATION.  
INTERFACE CIRCUIT AND DRIVER CIRCUIT APPLICATION.

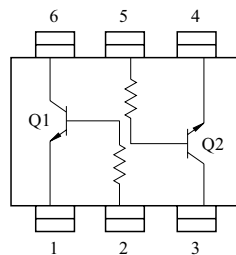
### FEATURES

- With Built-in Bias Resistors.
- Simplify Circuit Design.
- Reduce a Quantity of Parts and Manufacturing Process.
- High Packing Density.

### EQUIVALENT CIRCUIT



### EQUIVALENT CIRCUIT (TOP VIEW)



DIM	MILLIMETERS
A	2.00±0.20
A1	1.3±0.1
B	2.1±0.1
B1	1.25±0.1
C	0.65
D	0.2+0.10/-0.05
G	0-0.1
H	0.9±0.1
T	0.15+0.1/-0.05

US6

### MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current	I <sub>C</sub>	100	mA

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector Power Dissipation	P <sub>C</sub> *	200	mW
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature Range	T <sub>stg</sub>	-55 ~ 150	°C

\* Total Rating.

### ELECTRICAL CHARACTERISTICS (Ta=25°C)

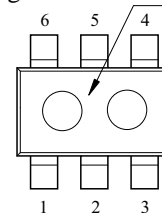
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Collector Cut-off Current	I <sub>CBO</sub>	V <sub>CB</sub> =50V, I <sub>E</sub> =0	-	-	100	nA	
Emitter Cut-off Current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0	-	-	100	nA	
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =1mA	120	-	-		
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA	-	0.1	0.3	V	
Transition Frequency	f <sub>T</sub> *	V <sub>CE</sub> =10V, I <sub>C</sub> =5mA	-	250	-	MHz	
Input Resistor	KRC860U	R <sub>1</sub>		-	4.7	-	k Ω
	KRC861U			-	10	-	
	KRC862U			-	100	-	
	KRC863U			-	22	-	
	KRC864U			-	47	-	

Note : \* Characteristic of Transistor Only.

### MARK SPEC

TYPE	KRC860U	KRC861U	KRC862U	KRC863U	KRC864U
MARK	NK	NM	NN	NO	NP

Marking Type Name

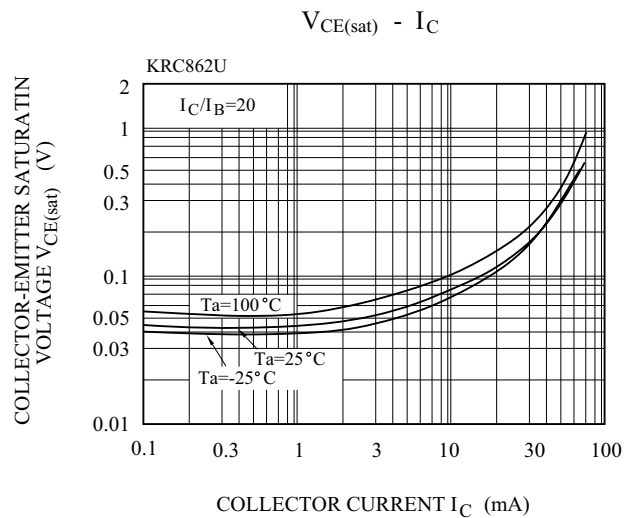
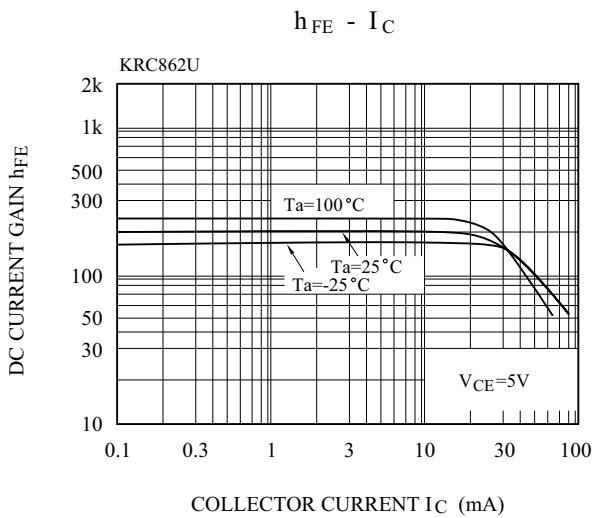
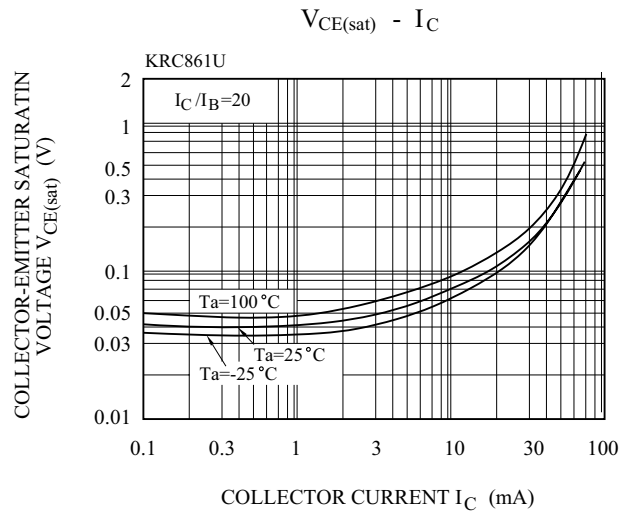
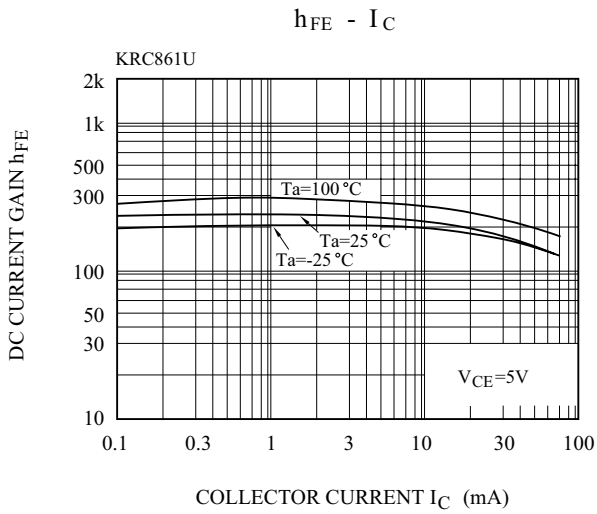
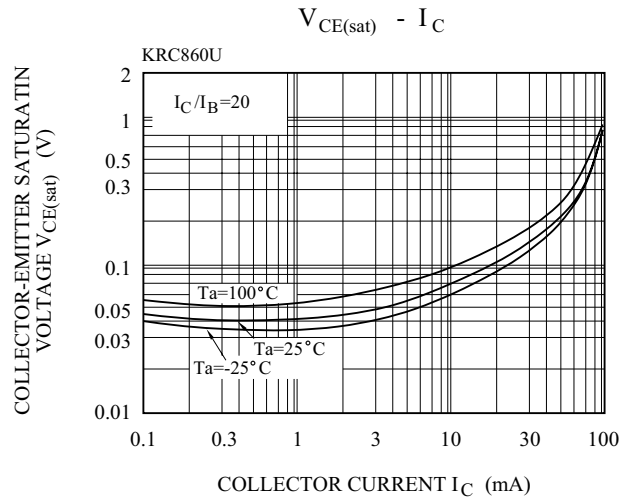
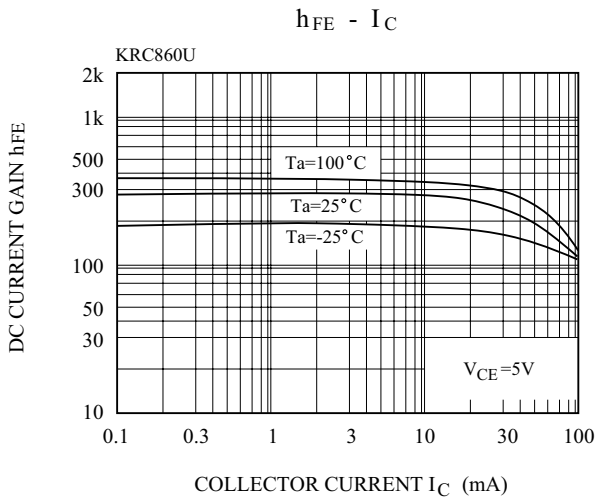


# KRC860U~KRC864U

## ELECTRICAL CHARACTERISTICS (Ta=25 °C)

CHARACTERISTIC			SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Switching Time	Rise Time	KRC860U	$t_r$	$V_O=5V$ $V_{IN}=5V$ $R_L=1k\ \Omega$	-	0.025	-	$\mu S$
		KRC861U			-	0.03	-	
		KRC862U			-	0.3	-	
		KRC863U			-	0.06	-	
		KRC864U			-	0.11	-	
	Storage Time	KRC860U	$t_{stg}$		-	3.0	-	
		KRC861U			-	2.0	-	
		KRC862U			-	6.0	-	
		KRC863U			-	4.0	-	
		KRC864U			-	5.0	-	
	Fall Time	KRC860U	$t_f$		-	0.2	-	
		KRC861U			-	0.12	-	
		KRC862U			-	2.0	-	
		KRC863U			-	0.9	-	
		KRC864U			-	1.4	-	

# KRC860U~KRC864U



# KRC860U~KRC864U

